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MMVL809T1

Silicon Tuning Diode

This device is designed for 900 MHz frequency control and tuning applications. It provides solid-state reliability in replacement of mechanical tuning methods.

Features

- Controlled and Uniform Tuning Ratio
- Surface Mount Package
- Available in 8 mm Tape and Reel
- Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	20	Vdc
Peak Forward Current	IF	20	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, T _A = 25°C (Note 1) Derate above 25°C	P _D	200 1.57	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	635	°C/W
Junction and Storage Temperature	T _J , T _{stg}	150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 Minimum Pad



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4.5 – 6.1 pF VOLTAGE VARIABLE CAPACITANCE DIODE





PLASTIC SOD-323 CASE 477 STYLE 1

MARKING DIAGRAM



5K = Device Code M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMVL809T1	SOD-323	3000 / Tape & Reel
MMVL809T1G	SOD-323 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

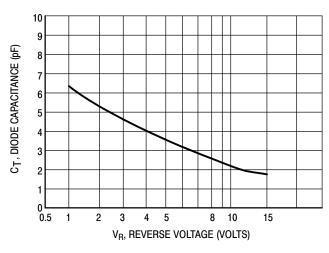
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage ($I_R = 10 \mu Adc$)	$V_{(BR)R}$	20	-	-	Vdc
Reverse Voltage Leakage Current (V _R = 15 Vdc)	I _R	-	_	50	nAdc

	C _t , Diode Capacitance V _R = 2.0 Vdc, f = 1.0 MHz pF		Q, Figure of Merit V _R = 3.0 Vdc f = 500 MHz	C _R , Capacitance Ratio C ₂ /C ₈ (Note 2) f = 1.0 MHz		
Device	Min Typ Max		Тур	Min	Max	
MMVL809T1	4.5	5.3	6.1	75	1.8	2.6

^{2.} C_R is the ratio of C_t measured at 2.0 Vdc divided by C_t measured at 8.0 Vdc.

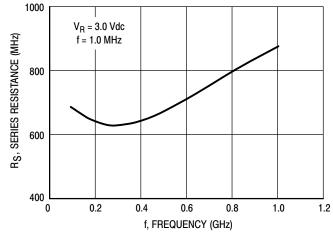
TYPICAL CHARACTERISTICS



1000 V_R = 3 Vdc T_A = 25°C

Figure 1. Diode Capacitance

Figure 2. Figure of Merit



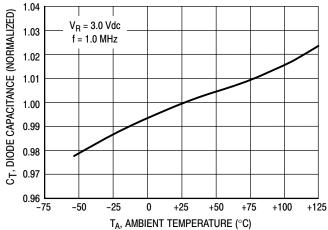
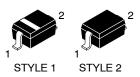


Figure 3. Series Resistance

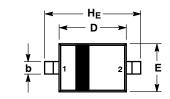
Figure 4. Diode Capacitance

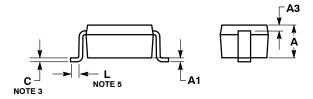


SOD-323 CASE 477-02 **ISSUE H**

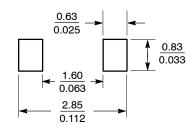
DATE 13 MAR 2007

SCALE 4:1





SOLDERING FOOTPRINT*

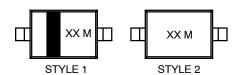


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS.
 5. DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS				INCHES	;	
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.031	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A3	().15 REI	F 0.006 REF		0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016	
С	0.089	0.12	0.177	0.003	0.005	0.007	
D	1.60	1.70	1.80	0.062	0.066	0.070	
E	1.15	1.25	1.35	0.045	0.049	0.053	
L	0.08			0.003			
HE	2.30	2.50	2.70	0.090	0.098	0.105	

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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DESCRIPTION:	SOD-323		PAGE 1 OF 1	

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